



Vincotech

flow PACK 0		1200 V / 10 A
Features		
• IGBT M7 with low V_{CESat} and improved EMC behavior • Compact and low inductive design • Built-in NTC		
Target applications		flow 0 12 mm housing
• Industrial Drives		
Types		Schematic
• 10-FZ126PA010M7-P867F78		

Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Inverter Switch				
Collector-emitter voltage	V_{CES}		1200	V
Collector current	I_C	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	14	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	20	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	61	W
Gate-emitter voltage	V_{GES}		± 20	V
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$



10-FZ126PA010M7-P867F78

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Maximum Ratings

$T_j = 25 \text{ }^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Inverter Diode				
Peak repetitive reverse voltage	V_{RRM}		1200	V
Continuous (direct) forward current	I_F	$T_j = T_{jmax}$	14	A
Repetitive peak forward current	I_{FRM}		20	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$	50	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Module Properties

Thermal Properties

Storage temperature	T_{stg}		-40...+125	$^\circ\text{C}$
Operation temperature under switching condition	T_{jop}		-40...($T_{jmax} - 25$)	$^\circ\text{C}$

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage*	$t_p = 2 \text{ s}$	6000	V
		AC Voltage	$t_p = 1 \text{ min}$	2500	V
Creepage distance				>12,7	mm
Clearance				9,22	mm
Comparative Tracking Index	CTI			> 200	

*100 % tested in production



10-FZ126PA010M7-P867F78

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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit	
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_c [A]	I_D [A]	T_j [°C]	I_F [A]	Min	Typ	Max

Inverter Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{GE} = V_{CE}$			0,001	25		5,4	6	6,6	V
Collector-emitter saturation voltage	V_{CESat}		15		10	125 150			1,65 1,90 1,95	1,95	V
Collector-emitter cut-off current	I_{CES}		0	1200		25			55	μA	
Gate-emitter leakage current	I_{GES}		20	0		25			500	nA	
Internal gate resistance	r_g							none		Ω	
Input capacitance	C_{ies}		0	10	25			2000		pF	
Output capacitance	C_{oes}										
Reverse transfer capacitance	C_{res}										
Gate charge	Q_g		15	600	10	25		80		nC	

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						1,57		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{goff} = 32 \Omega$ $R_{gon} = 32 \Omega$	± 15	600	10	25		128			ns
Rise time	t_r					125		126			
Turn-off delay time	$t_{d(off)}$					150		123			
Fall time	t_f	$Q_{fFWD} = 1,1 \mu\text{C}$ $Q_{rFWD} = 1,7 \mu\text{C}$ $Q_{rFWD} = 1,8 \mu\text{C}$	± 15	600	10	25		29			mWs
Turn-on energy (per pulse)	E_{on}					125		32			
Turn-off energy (per pulse)	E_{off}					150		34			
						25		145			
						125		179			
						150		182			
						25		98			
						125		108			
						150		117			
						25		0,883			
						125		1,125			
						150		1,189			
						25		0,656			
						125		0,860			
						150		0,908			



10-FZ126PA010M7-P867F78

datasheet

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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

Inverter Diode

Static

Forward voltage	V_F				10	25 125 150		1,61 1,69 1,69	2,1		V
Reverse leakage current	I_R			1200		25			25		µA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						1,91			K/W
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Dynamic

Peak recovery current	I_{RRM}	$di/dt = 278 \text{ A/}\mu\text{s}$ $di/dt = 270 \text{ A/}\mu\text{s}$ $di/dt = 272 \text{ A/}\mu\text{s}$	± 15	600	10	25 125 150		9 9 9			A
Reverse recovery time	t_{rr}					25 125 150		254 373 409			ns
Recovered charge	Q_r					25 125 150		1,088 1,664 1,808			µC
Reverse recovered energy	E_{rec}					25 125 150		0,374 0,620 0,680			mWs
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					25 125 150		85 54 49			A/µs

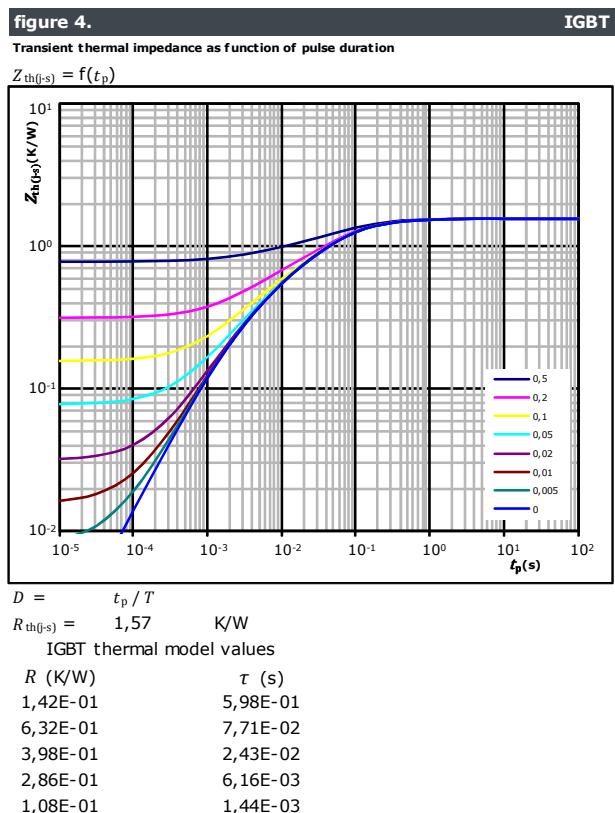
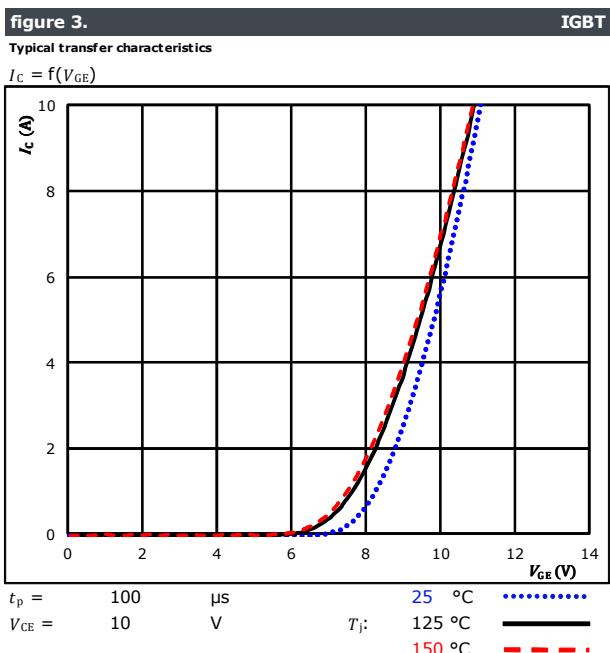
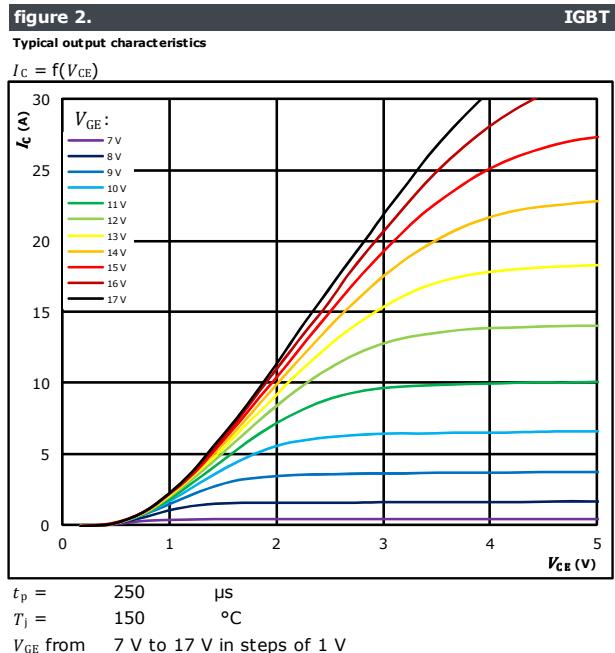
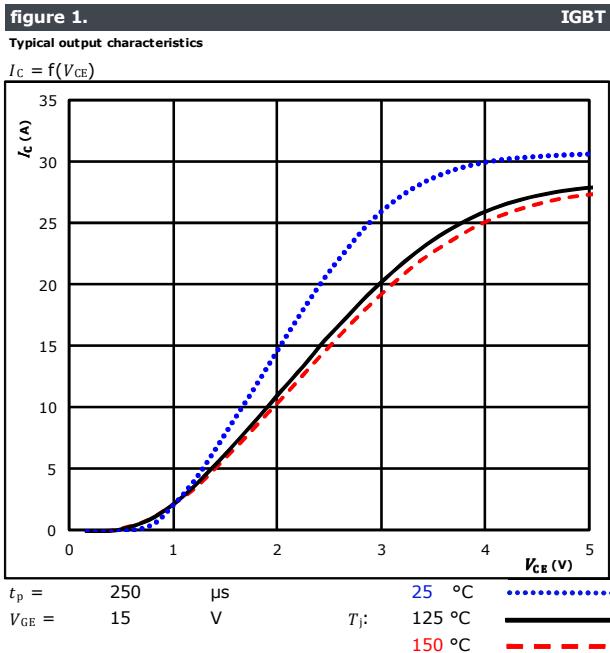
Thermistor

Rated resistance	R					25		22			kΩ
Deviation of R_{100}	$\Delta_{R/R}$	$R_{100} = 1484 \Omega$				100	-5		5		%
Power dissipation	P					25		5			mW
Power dissipation constant						25		1,5			mW/K
B-value	$B_{(25/50)}$	Tol. ±1 %				25		3962			K
B-value	$B_{(25/100)}$	Tol. ±1 %				25		4000			K
Vincotech NTC Reference									I		



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Inverter Switch Characteristics

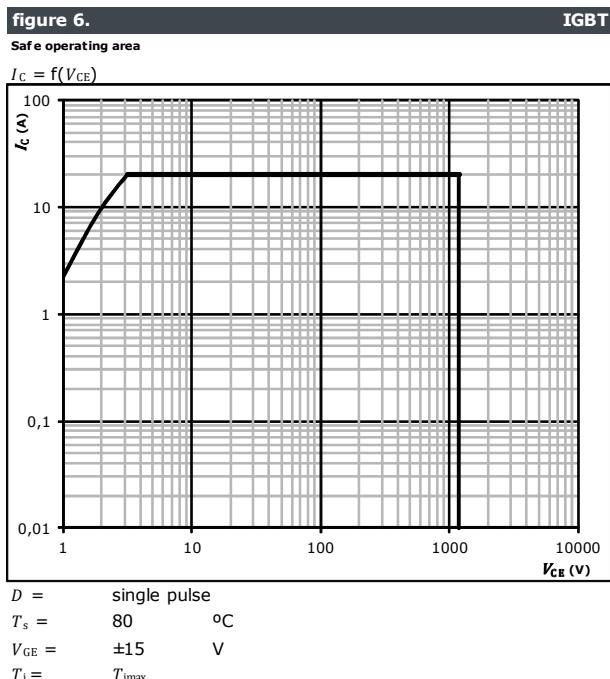




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datasheet

Inverter Switch Characteristics



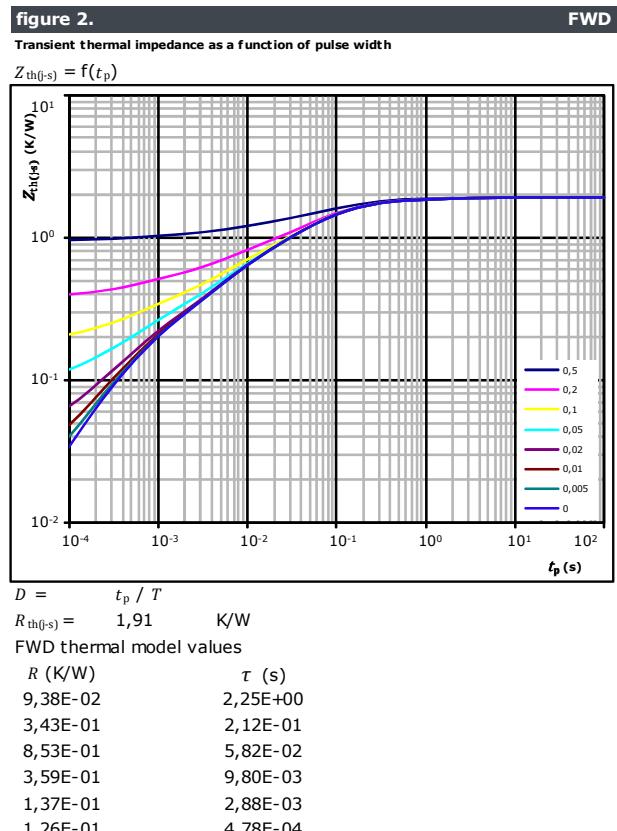
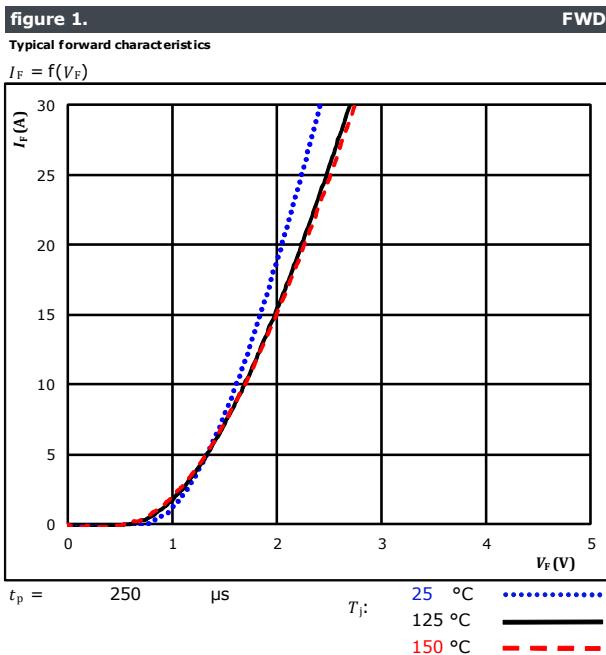


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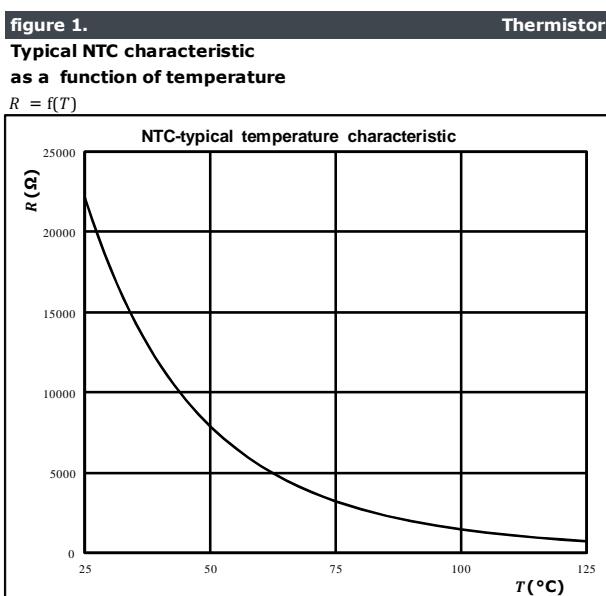
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Inverter Diode Characteristics



Thermistor Characteristics





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Inverter Switching Characteristics

figure 1.

Typical switching energy losses as a function of collector current

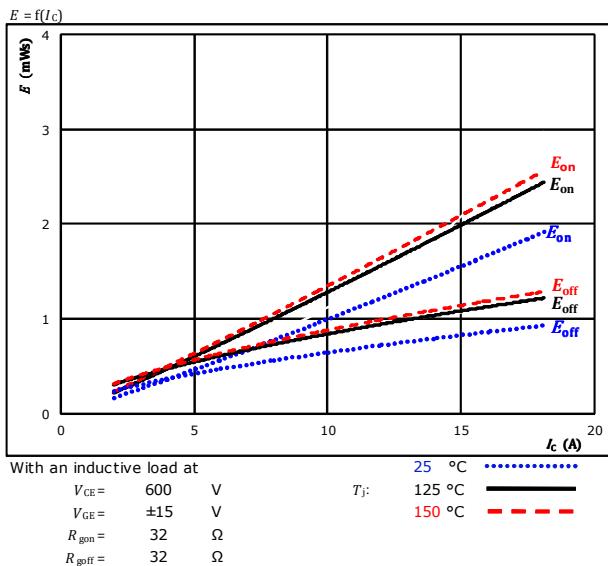


figure 2.

Typical switching energy losses as a function of gate resistor

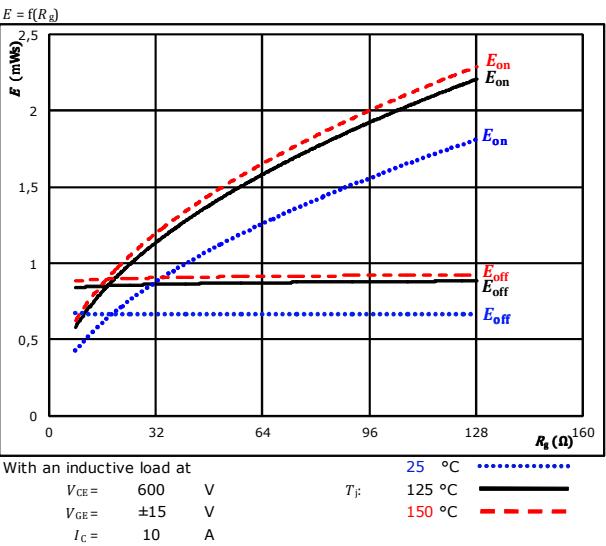


figure 3.

Typical reverse recovered energy loss as a function of collector current

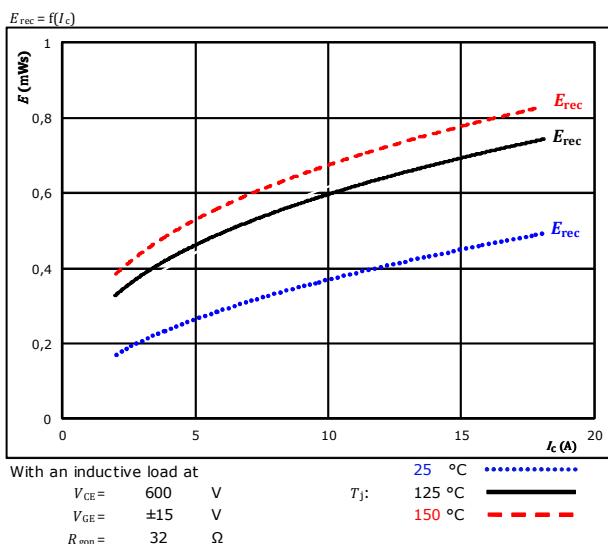
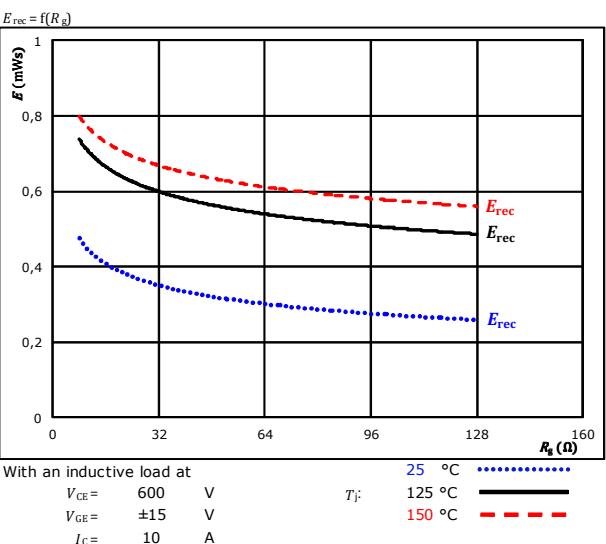


figure 4.

Typical reverse recovered energy loss as a function of gate resistor



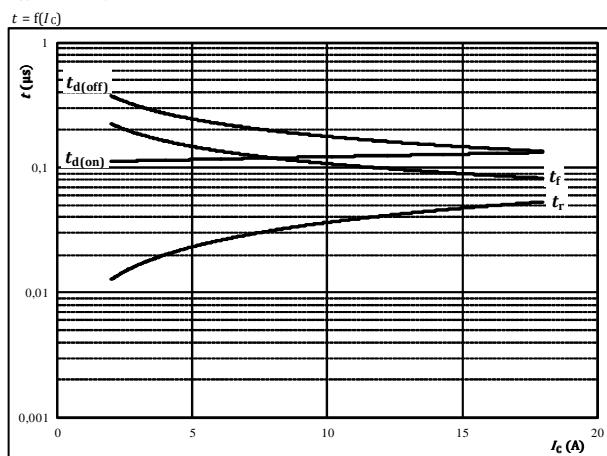


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Inverter Switching Characteristics

figure 5.

Typical switching times as a function of collector current



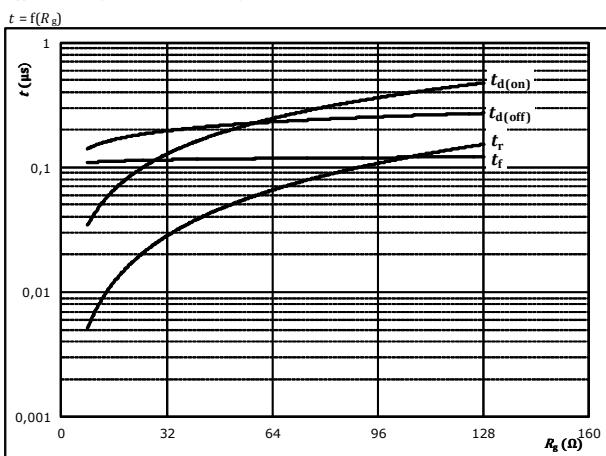
With an inductive load at

T _j =	150	°C
V _{CE} =	600	V
V _{GE} =	±15	V
R _{gon} =	32	Ω
R _{goff} =	32	Ω

IGBT

figure 6.

Typical switching times as a function of gate resistor



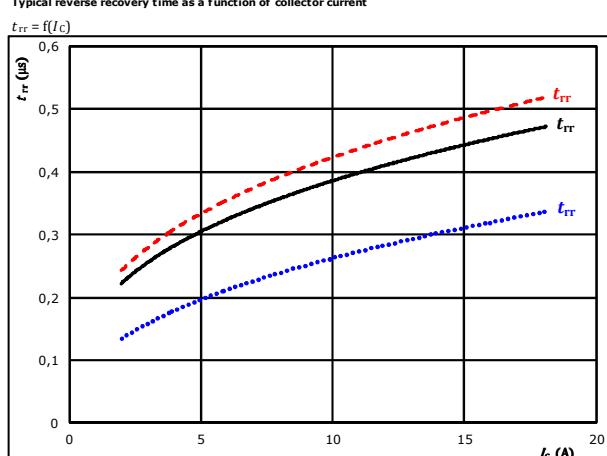
With an inductive load at

T _j =	150	°C
V _{CE} =	600	V
V _{GE} =	±15	V
I _C =	10	A

IGBT

figure 7.

Typical reverse recovery time as a function of collector current

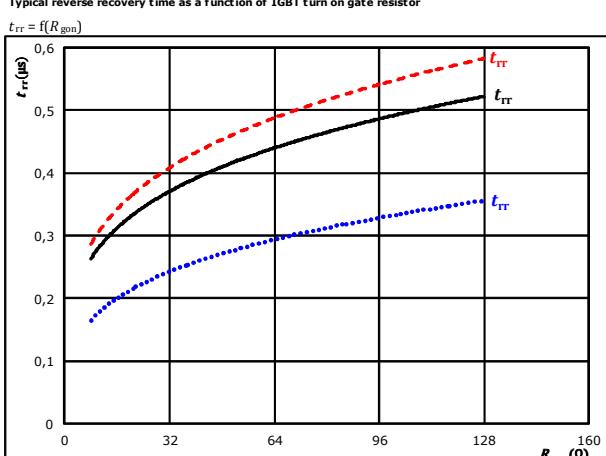


At V_{CE} = 600 V 25 °C -----
V_{GE} = ±15 V T_j = 125 °C ————
R_{gon} = 32 Ω 150 °C - - - - -

FWD

figure 8.

Typical reverse recovery time as a function of IGBT turn on gate resistor



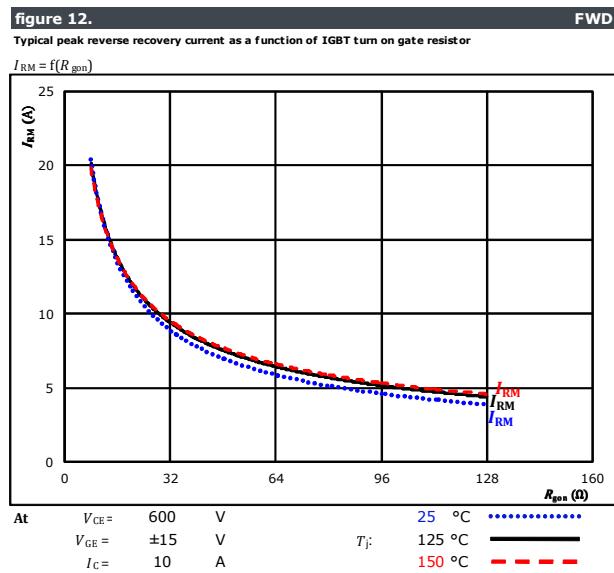
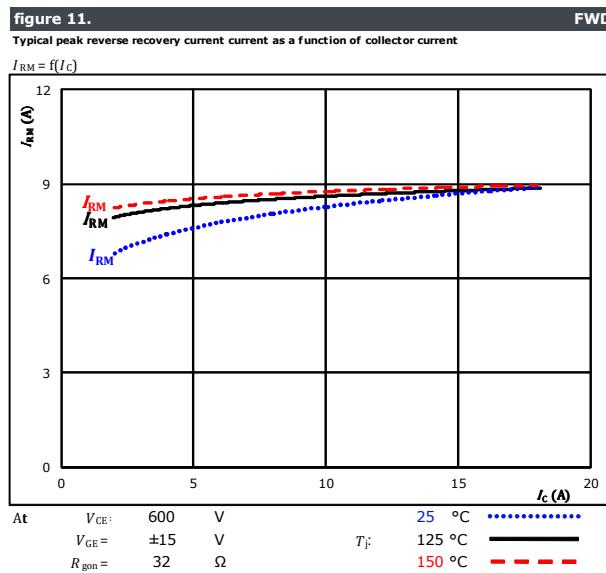
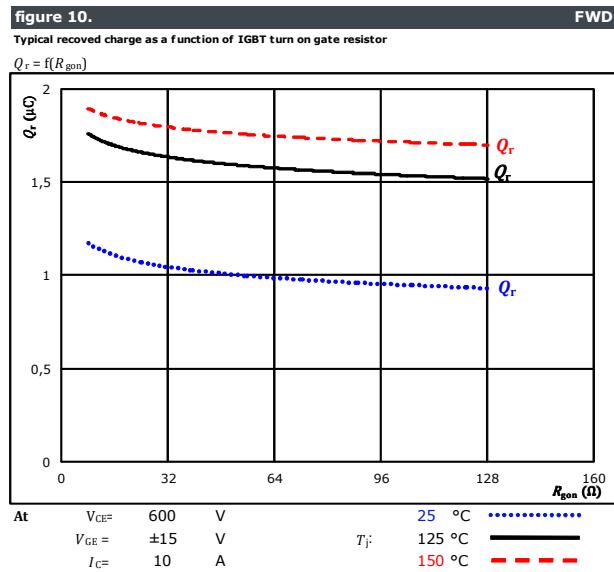
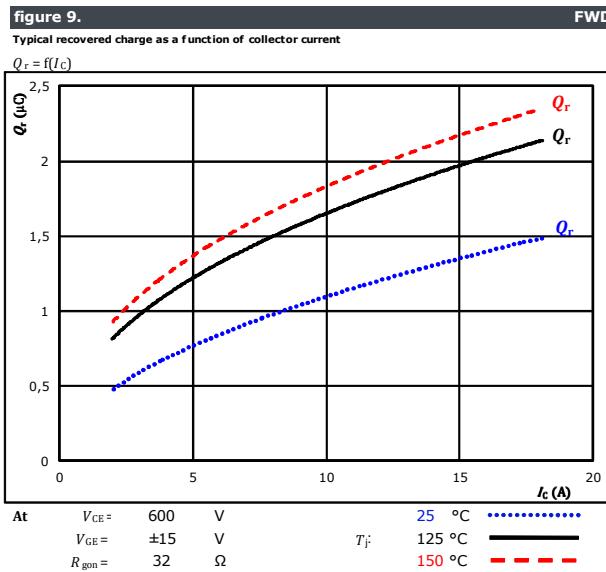
At V_{CE} = 600 V 25 °C -----
V_{GE} = ±15 V T_j = 125 °C ————
I_C = 10 A 150 °C - - - - -

FWD



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Inverter Switching Characteristics





10-FZ126PA010M7-P867F78

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Inverter Switching Characteristics

figure 13.

Typical rate of fall of forward and reverse recovery current as a function of collector current

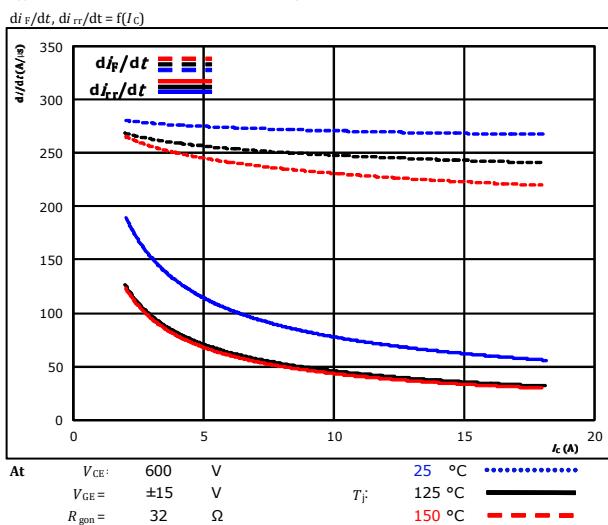


figure 14.

Typical rate of fall of forward and reverse recovery current as a function of IGBT turn on gate resistor

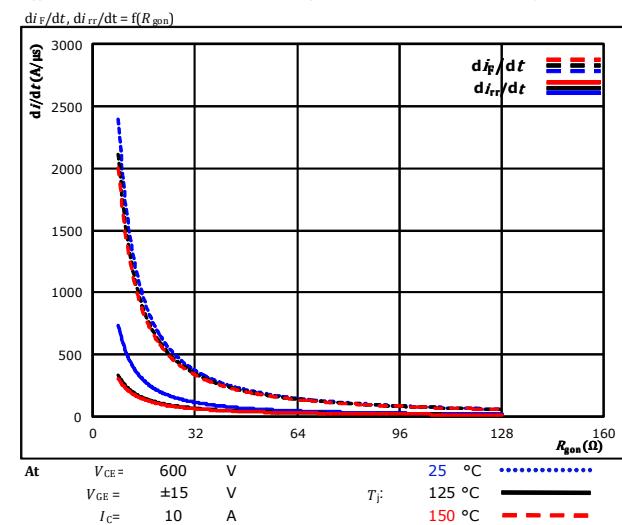
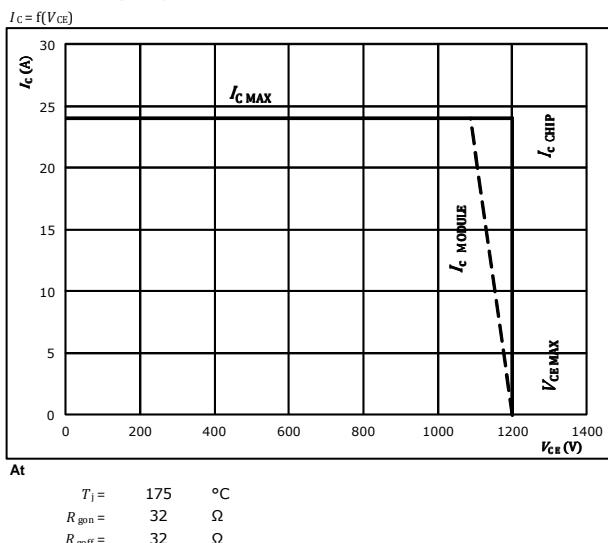


figure 15.

Reverse bias safe operating area





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Inverter Switching Definitions

General conditions

T_j	=	125 °C
R_{gon}	=	32 Ω
R_{goff}	=	32 Ω

figure 1.

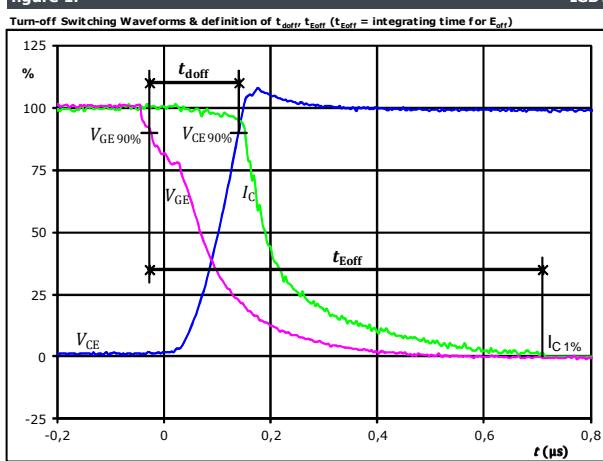
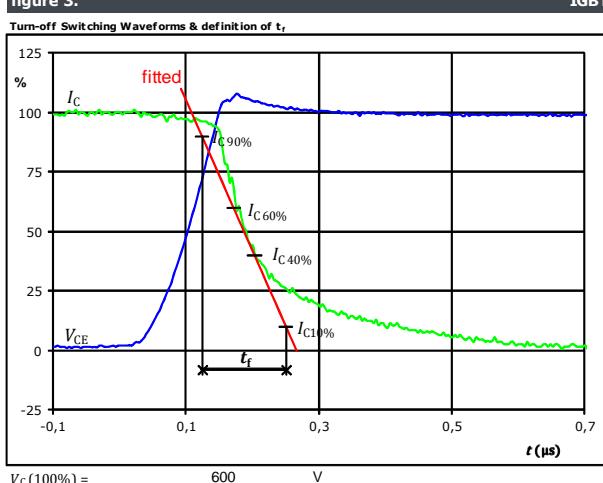


figure 3.

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figure 2.

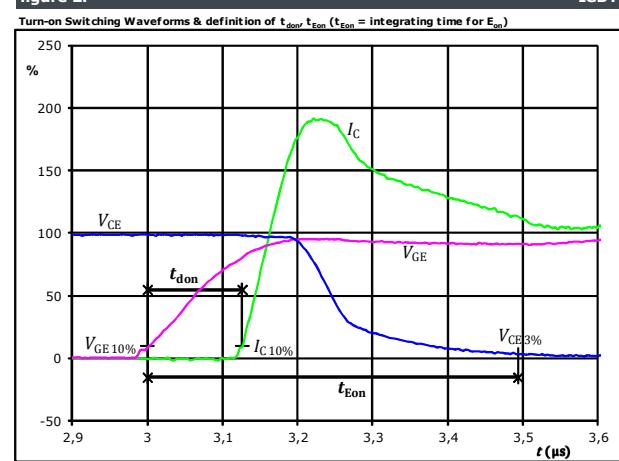
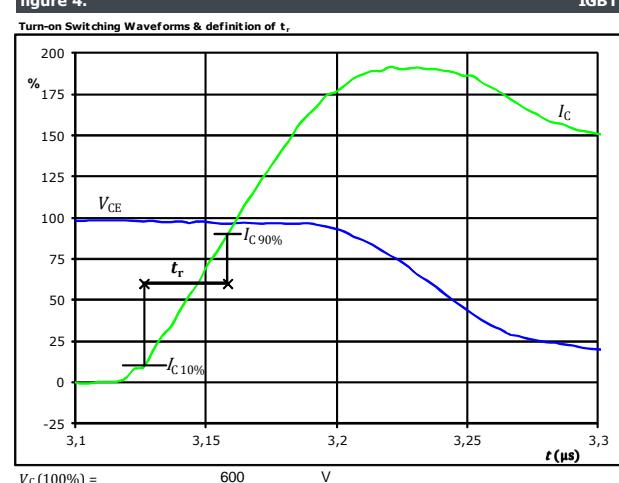


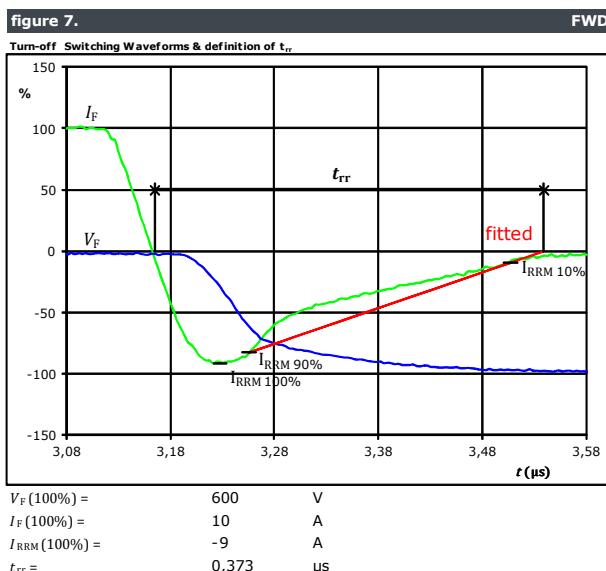
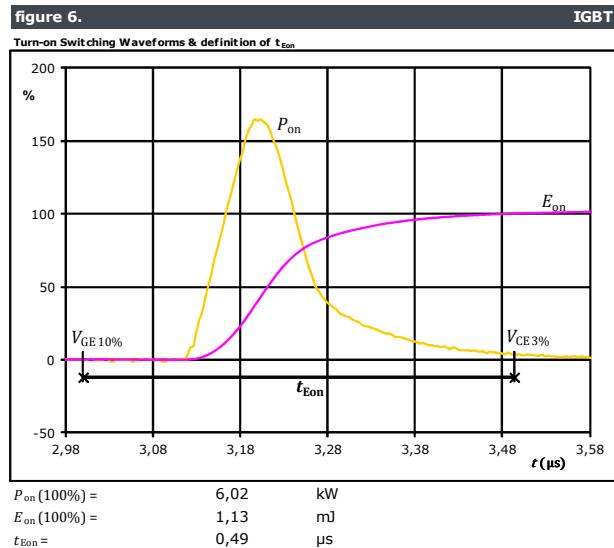
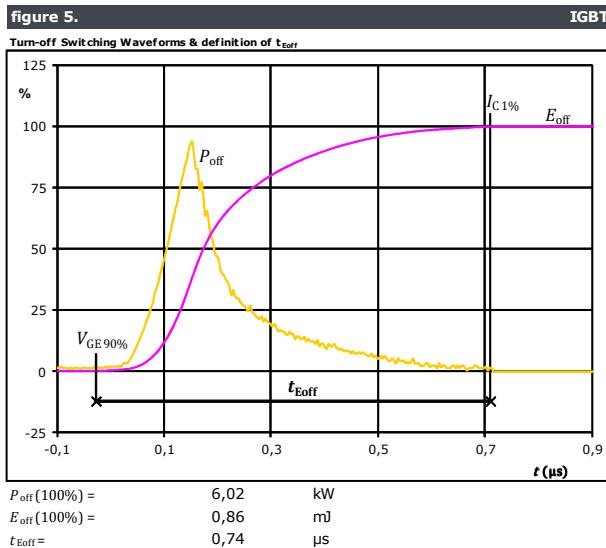
figure 4.





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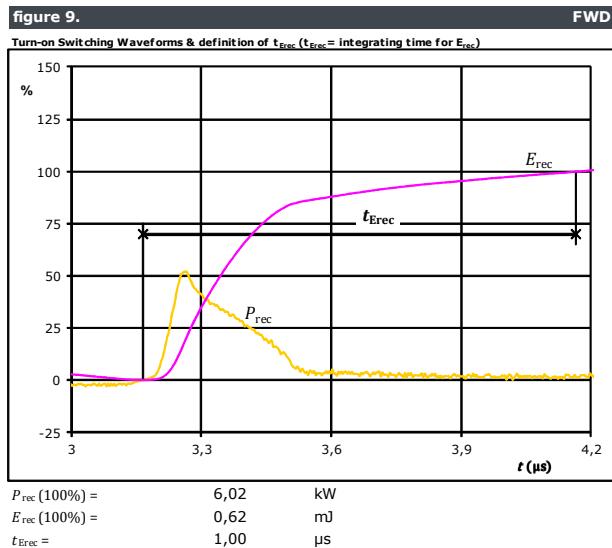
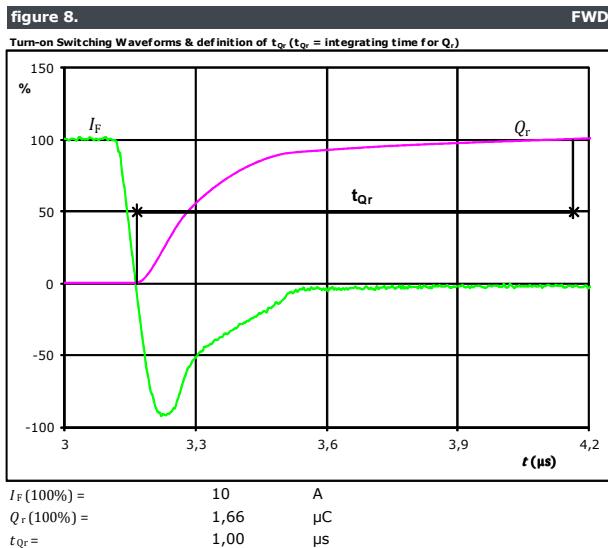
Inverter Switching Characteristics





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Inverter Switching Characteristics



**10-FZ126PA010M7-P867F78**

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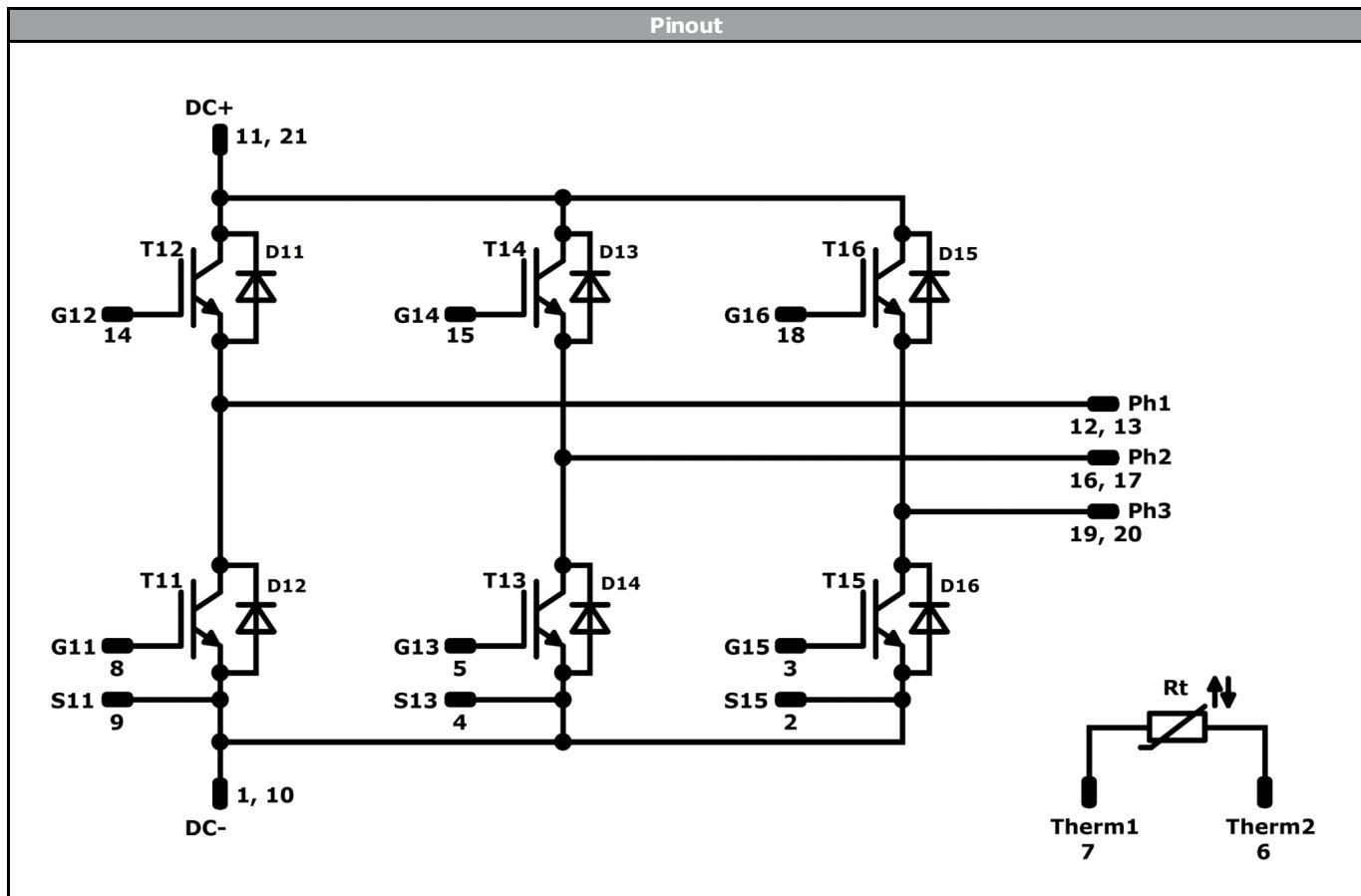
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Ordering Code & Marking							
Version				Ordering Code			
without thermal paste 12 mm housing with solder pins				10-FZ126PA010M7-P867F78			
NNNNNNNNNNNNNN TTTTTTVVWWYY UL VIN LLLL SSSS							
NNNNNNNNNNNNNN TTTTTTVVWWYY UL VIN LLLL SSSS			Text	Name	Date code	UL & VIN	Lot
				NNNNNNNNNNNNNN-TTTTTW	WWYY	UL VIN	LLLLL
			Datamatrix	Type&Ver	Lot number	Serial	Date code
				TTTTTTVV	LLLLL	SSSS	WWYY

Outline							
Pin table				Tolerance of pinpositions: $\pm 0.5\text{mm}$ at the end of pins Dimension of coordinate axis is only offset without tolerance			
Pin	X	Y	Function	1	33,3	0	DC-
2	30,7	0	S15	3	27,9	0	G15
4	23,85	0	S13	5	21,05	0	G13
6	15,95	0	Therm2	7	9,6	0	Therm1
8	5,4	0	G11	9	2,6	0	S11
10	0	0	DC-	11	0	11,15	DC+
12	0	22,3	Ph1	13	2,6	22,3	Ph1
14	5,5	22,3	G12	15	13,1	22,3	G14
16	15,9	22,3	Ph2	17	19,4	22,3	Ph2
18	27,7	22,3	G16	19	30,7	22,3	Ph3
20	33,3	22,3	Ph3	21	33,3	11,15	DC+



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Identification					
ID	Component	Voltage	Current	Function	Comment
T11-T16	IGBT	1200 V	10 A	Inverter Switch	
D11-D16	FWD	1200 V	10 A	Inverter Diode	
Rt	NTC			Thermistor	



10-FZ126PA010M7-P867F78

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Packaging instruction			
Standard packaging quantity (SPQ) 135	>SPQ	Standard	<SPQ Sample

Handling instruction			
Handling instructions for flow 0 packages see vincotech.com website.			

Package data			
Package data for flow 0 packages see vincotech.com website.			

UL recognition and file number			
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.			

Document No.:	Date:	Modification:	Pages
10-FZ126PA010M7-P867F78-D1-14	27 Sep. 2017		

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.